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SLLS829C - APRIL 2007 - REVISED MARCH 2011

# RS-232 TRANSCEIVER WITH SPLIT SUPPLY PIN FOR LOGIC SIDE

Check for Samples: TRS3386E

#### **FEATURES**

- V<sub>L</sub> Pin for Compatibility With Mixed-Voltage Systems Down to 2.5 V on Logic Side
- Enhanced ESD Protection on RIN Inputs and DOUT Outputs
  - ±15-kV Human-Body Model
  - ±15-kV IEC 61000-4-2, Air-Gap Discharge
  - ±8-kV IEC 61000-4-2, Contact Discharge
- Low 300-µA Supply Current
- Specified 250-kbps Data Rate
- 1-µA Low-Power Shutdown
- Meets EIA/TIA-232 Specifications Down to 3 V
- Designed to be Interchangeable With Industry Standard '3386 Devices

#### APPLICATIONS

- Hand-Held Equipment
- PDAs
- Cell Phones
- · Battery-Powered Equipment
- Data Cables

#### PW OR DW PACKAGE **TOP VIEW** 20 PWRDOWN 19 V<sub>CC</sub> 18 GND C1-l 3 17 DOUT1 C2+ 4 16 DOUT2 C2- 5 V- 6 15 DOUT3 DIN1 7 14 RIN1 DIN2 8 13 RIN2 DIN3 9 12 V<sub>I</sub> 11 ROUT1 ROUT2 10

# **DESCRIPTION/ORDERING INFORMATION**

The TRS3386E is a three-driver and two-receiver RS-232 interface device, with split supply pins for mixed-signal operations. All RS-232 inputs and outputs are protected to ±15 kV using the IEC 61000-4-2 Air-Gap Discharge method, ±8 kV using the IEC 61000-4-2 Contact Discharge method, and ±15 kV using the Human-Body Model.

The charge pump requires only four small 0.1-µF capacitors for operation from a 3.3-V supply. The TRS3386E is capable of running at data rates up to 250 kbps, while maintaining RS-232-compliant output levels.

The TRS3386E has a unique  $V_L$  pin that allows operation in mixed-logic voltage systems. Both driver in (DIN) and receiver out (ROUT) logic levels are pin programmable through the  $V_L$  pin. The TRS3386E is available in a space-saving thin shrink small-outline package (TSSOP).

## ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)</sup> (2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	TSSOP – PW	TRS3386ECPWR	RV86EC
	SOIC - DW	TRS3386ECDWR	TRS3386EC
–40°C to 85°C	TSSOP – PW	TRS3386EIPWR	RV86EI
-40 C to 65 C	SOIC - DW	TRS3386EIDWR	TRS3386EI

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

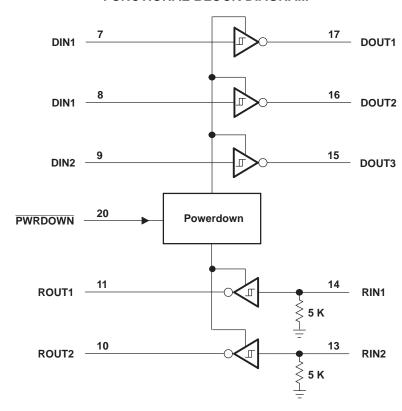
<sup>(2)</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.



# Table 1. TRUTH TABLE (SHUTDOWN FUNCTION)

PWRDWN	DRIVER OUTPUTS	RECEIVER OUTPUTS	CHARGE PUMP	
L	High-Z	High-Z	Inactive	
Н	Active	Active	Active	

# **FUNCTIONAL BLOCK DIAGRAM**



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#### **TERMINAL FUNCTIONS**

TERMIN	NAL	DESCRIPTION						
NAME	NO.							
C1+	1	Positive terminal of the voltage-doubler charge-pump capacitor						
V+	2	5.5-V supply generated by the charge pump						
C1-	3	Negative terminal of the voltage-doubler charge-pump capacitor						
C2+	4	Positive terminal of the inverting charge-pump capacitor						
C2-	5	Negative terminal of the inverting charge-pump capacitor						
V-	6	–5.5-V supply generated by the charge pump						
DIN1 DIN2 DIN3	7 8 9	Driver inputs						
ROUT2 ROUT1	10 11	Receiver outputs. Swing between 0 and V <sub>L</sub> .						
$V_L$	12	Logic-level supply. All CMOS inputs and outputs are referenced to this supply.						
RIN2 RIN1	13 14	RS-232 receiver inputs						
DOUT3 DOUT2 DOUT1	15 16 17	RS-232 driver outputs						
GND	18	Ground						
V <sub>CC</sub>	19	3-V to 5.5-V supply voltage						
PWRDWN	20	Powerdown input L = Powerdown H = Normal operation						

# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
	V <sub>CC</sub> to GND		-0.3	6	V
	V <sub>L</sub> to GND		-0.3	V <sub>CC</sub> + 0.3	V
	V+ to GND		-0.3	7	V
	V- to GND		0.3	<b>-</b> 7	V
	V+ +  V-  <sup>(2)</sup>			13	V
.,	land traite an	DIN, PWRDWN to GND	-0.3	6	
VI	Input voltage	RIN to GND		±25	V
.,	Outrout walte as	DOUT to GND		±13.2	V
Vo	Output voltage	ROUT	-0.3	V <sub>L</sub> + 0.3	
	Short-circuit duration DOUT to GND	•	-0.3 V <sub>CC</sub> + 0.3 -0.3 7 0.3 -7 13 -0.3 6 ±25 ±13.2		
	Continuous power dissipation	T <sub>A</sub> = 70°C, 20-pin TSSOP (derate 7 mW/°C above 70°C)		559	mW
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C
	Lead temperature (soldering, 10 s)			300	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

<sup>(2)</sup> V+ and V- can have maximum magnitudes of 7 V, but their absolute difference cannot exceed 13 V.



# **Recommended Operating Conditions**

				MIN	MAX	UNIT
$V_{CC}$	Supply voltage			3	5.5	V
$V_L$	Supply voltage			2.25	V <sub>CC</sub>	V
	Input logic threshold low DIN, PWRDWN	V <sub>L</sub> = 3 V or 5.5 V		8.0	\/	
	Input logic threshold low	ogic threshold low DIN, PWRDWN	V <sub>L</sub> = 2.3 V		0.6	V
	Input logic threshold high DIN, PWRDWN	V <sub>L</sub> = 5.5 V	2.4			
		DIN, PWRDWN	V <sub>L</sub> = 3 V	2.0		V
			$V_{L} = 2.7 \text{ V}$	1.4		
	0		TRS3386ECPWR	0	70	)
	Operating temperature		TRS3386EIPWR	-40	85	°C
	Receiver input voltage			-25	25	V

# **Electrical Characteristics**

over operating free-air temperature range,  $V_{CC}$  =  $V_L$  = 3 V to 5.5 V, C1–C4 = 0.1  $\mu$ F (tested at 3.3 V  $\pm$  10%), C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F (tested at 5 V  $\pm$  10%) (unless otherwise noted)

PARAMETER	TEST CONDITIONS MIN		TYP <sup>(1)</sup>	MAX	UNIT
DC Characteristics (V <sub>CC</sub> = 3.3 V or 5 V, T <sub>A</sub> = 25°C)					
Powerdown supply current	$\overline{PWRDWN}$ = GND, All inputs at $V_{CC}$ or GND		1	10	μΑ
Supply current	PWRDWN = V <sub>CC</sub> , No load		0.3	1	mA

<sup>(1)</sup> Typical values are at  $V_{CC} = V_L = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

# **ESD Protection**

PARAMETER	TEST CONDITIONS	TYP	UNIT
	Human-Body Model	±15	
RIN, DOUT	IEC 61000-4-2 Air-Gap Discharge	±15	kV
	IEC 61000-4-2 Contact Discharge	±8	

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#### RECEIVER SECTION

#### **Electrical Characteristics**

over operating free-air temperature range,  $V_{CC}$  =  $V_L$  = 3 V to 5.5 V, C1–C4 = 0.1  $\mu$ F (tested at 3.3 V  $\pm$  10%), C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F (tested at 5 V  $\pm$  10%),  $T_A$  =  $T_{MIN}$  to  $T_{MAX}$  (unless otherwise noted)

	PARAMETER	TEST (	CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
I <sub>off</sub>	Output leakage current	ROUT, receivers disab	led		±0.05	±10	μΑ
$V_{OL}$	Output voltage low	$I_{OUT} = 1.6 \text{ mA}$				0.4	V
$V_{OH}$	Output voltage high	$I_{OUT} = -1 \text{ mA}$	I <sub>OUT</sub> = -1 mA		$V_{L} - 0.1$		V
V	Innut throohold low	T <sub>A</sub> = 25°C	V <sub>L</sub> = 5 V	0.8	1.2		V
V <sub>IT</sub>	Input threshold low		$V_{L} = 3.3 \text{ V}$	0.6	1.5		
V	Innut throohold high	T 25°C	V <sub>L</sub> = 5 V		1.8	2.4	V
V <sub>IT+</sub>	Input threshold high	$T_A = 25$ °C $V_L = 3.3 \text{ V}$			1.5	2.4	V
V <sub>hys</sub>	Input hysteresis				0.5		V
	Input resistance	$T_A = 25^{\circ}C$		3	5	7	kΩ

<sup>(1)</sup> Typical values are at  $V_{CC} = V_L = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ 

# **Switching Characteristics**

over operating free-air temperature range,  $V_{CC} = V_L = 3 \text{ V}$  to 5.5 V, C1–C4 = 0.1  $\mu\text{F}$  (tested at 3.3 V  $\pm$  10%), C1 = 0.047  $\mu\text{F}$ , C2–C4 = 0.33  $\mu\text{F}$  (tested at 5 V  $\pm$  10%),  $T_A = T_{MIN}$  to  $T_{MAX}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS		UNIT
t <sub>PHL</sub>	Descriver propagation delay	Baselinar input to receiver output C 450 pF	0.15	
t <sub>PLH</sub>	Receiver propagation delay	Receiver input to receiver output, $C_L = 150 \text{ pF}$		μs
t <sub>PHL</sub> – t <sub>PLH</sub>	Receiver skew		50	ns
t <sub>en</sub>	Receiver output enable time	From PWRDWN	200	ns
t <sub>dis</sub>	Receiver output disable time	From PWRDWN	200	ns

<sup>(1)</sup> Typical values are at  $V_{CC} = V_L = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

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### **DRIVER SECTION**

#### **Electrical Characteristics**

over operating free-air temperature range,  $V_{CC}$  =  $V_L$  = 3 V to 5.5 V, C1–C4 = 0.1  $\mu$ F (tested at 3.3 V  $\pm$  10%), C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F (tested at 5 V  $\pm$  10%),  $T_A$  =  $T_{MIN}$  to  $T_{MAX}$  (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
$V_{OH}$	Output voltage swing	All driver outputs loaded with 3 $k\Omega$ to ground	±5	±5.4		V
r <sub>O</sub>	Output resistance	$V_{CC} = V + = V - = 0$ , Driver output = ±2 V	300	10M		Ω
Ios	Output short-circuit current	$V_{T\_OUT} = 0$			±60	mA
I <sub>OZ</sub>	Output leakage current	$V_{T\_OUT} = \pm 12 \text{ V, Driver disabled,}$ $V_{CC} = 0 \text{ or } 3 \text{ V to } 5.5 \text{ V}$			±25	μΑ
	Driver input hysteresis				0.5	V
	Input leakage current	DIN, PWRDWN		±0.01	±1	μΑ

<sup>(1)</sup> Typical values are at  $V_{CC} = V_L = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ 

# **Timing Requirements**

over operating free-air temperature range,  $V_{CC} = V_L = 3 \text{ V}$  to 5.5 V, C1–C4 = 0.1  $\mu\text{F}$  (tested at 3.3 V  $\pm$  10%), C1 = 0.047  $\mu\text{F}$ , C2–C4 = 0.33  $\mu\text{F}$  (tested at 5 V  $\pm$  10%),  $T_A = T_{MIN}$  to  $T_{MAX}$  (unless otherwise noted)

	PARAMETER			MIN	TYP <sup>(1)</sup>	MAX	UNIT
	Maximum data rate	$R_L = 3 \text{ k}\Omega, C_L = 1000 \text{ pF}, O$	<sub>CC</sub> = 3.3 V,				kbps
	Time-to-exit powerdown	V <sub>T_OUT</sub>   > 3.7 V			100		μs
t <sub>PHL</sub> - t <sub>PLH</sub>	Driver skew <sup>(2)</sup>				100		ns
		$V_{CC} = 3.3 \text{ V},$	C <sub>L</sub> = 150 pF to 1000 pF	6		30	
	$ \begin{array}{ll} \text{Transition-region} & \text{T}_{\text{A}} = 25^{\circ}\text{C}, \\ \text{R}_{\text{L}} = 3 \text{ k}\Omega \text{ to 7 k}\Omega, \\ \text{Measured from 3 V} \\ \text{to } -3 \text{ V or } -3 \text{ V to 3 V} \\ \end{array} $	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$ Measured from 3 V	C <sub>L</sub> = 150 pF to 2500 pF	4		30	V/µs

## **ESD Protection**

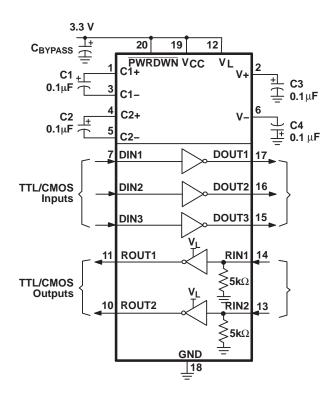
PARAMETER	TEST CONDITIONS	TYP	UNIT
	Human-Body Model	±15	
RIN, DOUT	IEC 61000-4-2 Air-Gap Discharge	±15	kV
	IEC 61000-4-2 Contact Discharge	±8	

Product Folder Link(s): TRS3386E

<sup>(1)</sup> Typical values are at  $V_{CC} = V_L = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . (2) Driver skew is measured at the driver zero crosspoint.

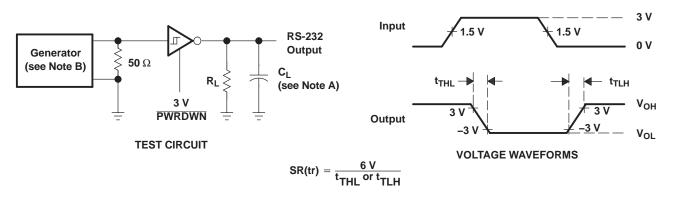


## **APPLICATION INFORMATION**





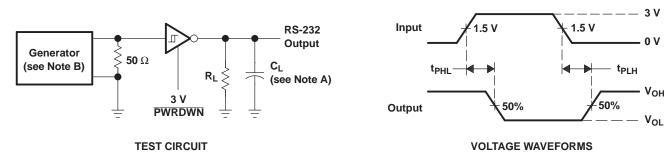
#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O$  = 50  $\Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.

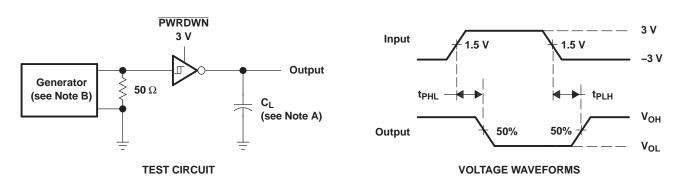
Figure 1. Driver Slew Rate



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O = 50 \Omega$ , 50% duty cycle,  $t_r \le 10$  ns.  $t_f \le 10$  ns.

Figure 2. Driver Pulse Skew



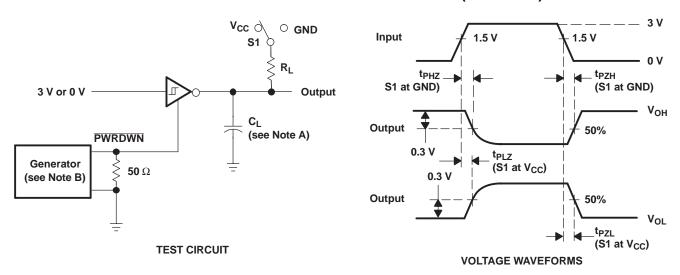
NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics:  $Z_O = 50 \ \Omega$ , 50% duty cycle,  $t_f \le 10 \ ns$ .

Figure 3. Receiver Propagation Delay Times



# PARAMETER MEASUREMENT INFORMATION (Continued)



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics:  $Z_O = 50~\Omega$ , 50% duty cycle,  $t_r \le 10$  ns.  $t_f \le 10$  ns.

Figure 4. Receiver Enable and Disable Times



# **REVISION HISTORY**

CI	hanges from Revision B (April 2009) to Revision C	Page
•	Changed V <sub>L</sub> Pin for Compatibility With Mixed-Voltage Systems Down to 2.5 V (originally 1.8 V) on the Logic Side	1
•	Changed V <sub>L</sub> Supply MIN value from 1.65 V to 2.25 V.	4
•	Deleted V <sub>L</sub> = 1.65V parameter from Input logic threshold low.	4
•	Deleted V <sub>L</sub> = 1.95V parameter from Input logic threshold high.	4

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
TDCCCCCCDWD	A =4:	Duadustian	COIC (DW)   20	2000 11 ADOF TOD	V	(4)	(5)	0 to 70	TDCCCCCC
TRS3386ECDWR	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS3386EC
TRS3386ECDWR.A	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS3386EC
TRS3386ECPW	Obsolete	Production	TSSOP (PW)   20	-	-	Call TI	Call TI	0 to 70	RV86EC
TRS3386ECPWR	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	RV86EC
TRS3386ECPWR.A	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	RV86EC
TRS3386ECPWRG4	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	RV86EC
TRS3386EIDWR	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS3386EI
TRS3386EIDWR.A	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS3386EI
TRS3386EIPW	Obsolete	Production	TSSOP (PW)   20	-	-	Call TI	Call TI	-40 to 85	RV86EI
TRS3386EIPWR	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	RV86EI
TRS3386EIPWR.A	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	RV86EI

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



# **PACKAGE OPTION ADDENDUM**

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# **PACKAGE MATERIALS INFORMATION**

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# TAPE AND REEL INFORMATION



# TAPE DIMENSIONS KO PI BO Cavity A0

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

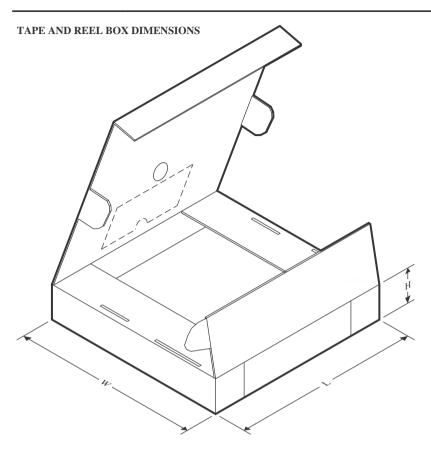
## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ı	TRS3386ECDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
	TRS3386ECPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
	TRS3386EIPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

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# \*All dimensions are nominal

Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
TRS3386ECDWR	SOIC	DW	20	2000	356.0	356.0	45.0	
TRS3386ECPWR	TSSOP	PW	20	2000	353.0	353.0	32.0	
TRS3386EIPWR	TSSOP	PW	20	2000	353.0	353.0	32.0	



SOIC



### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



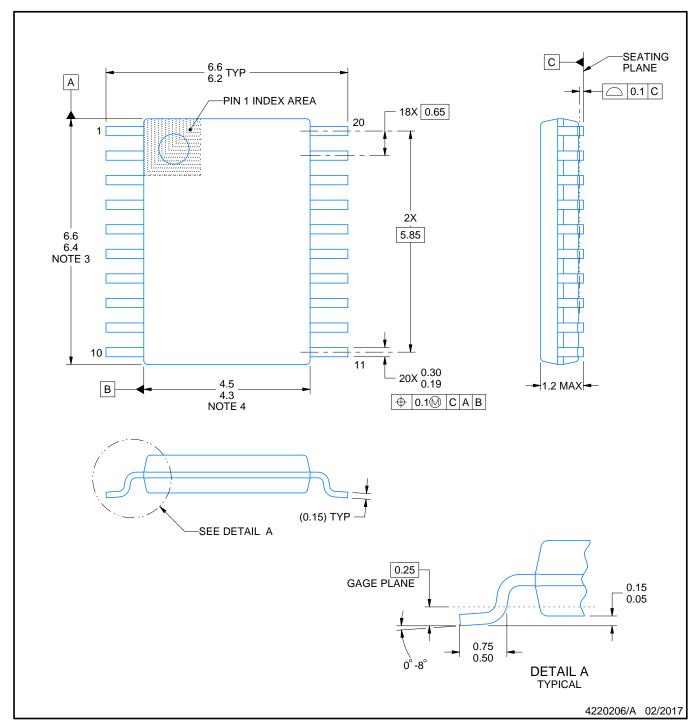
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



### NOTES:

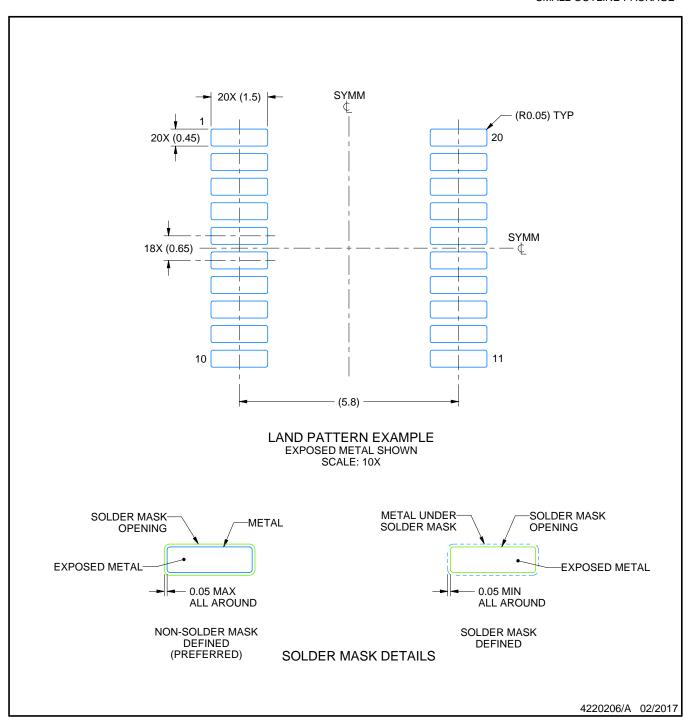
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



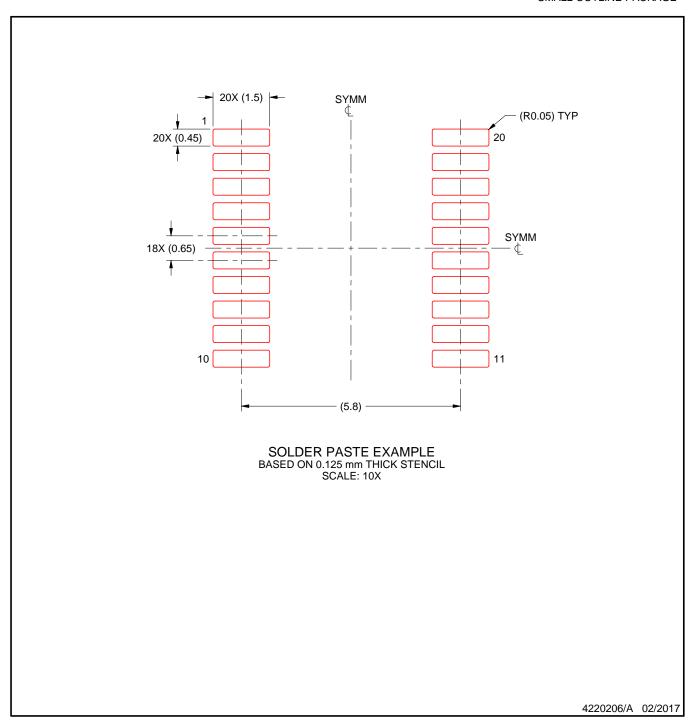
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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